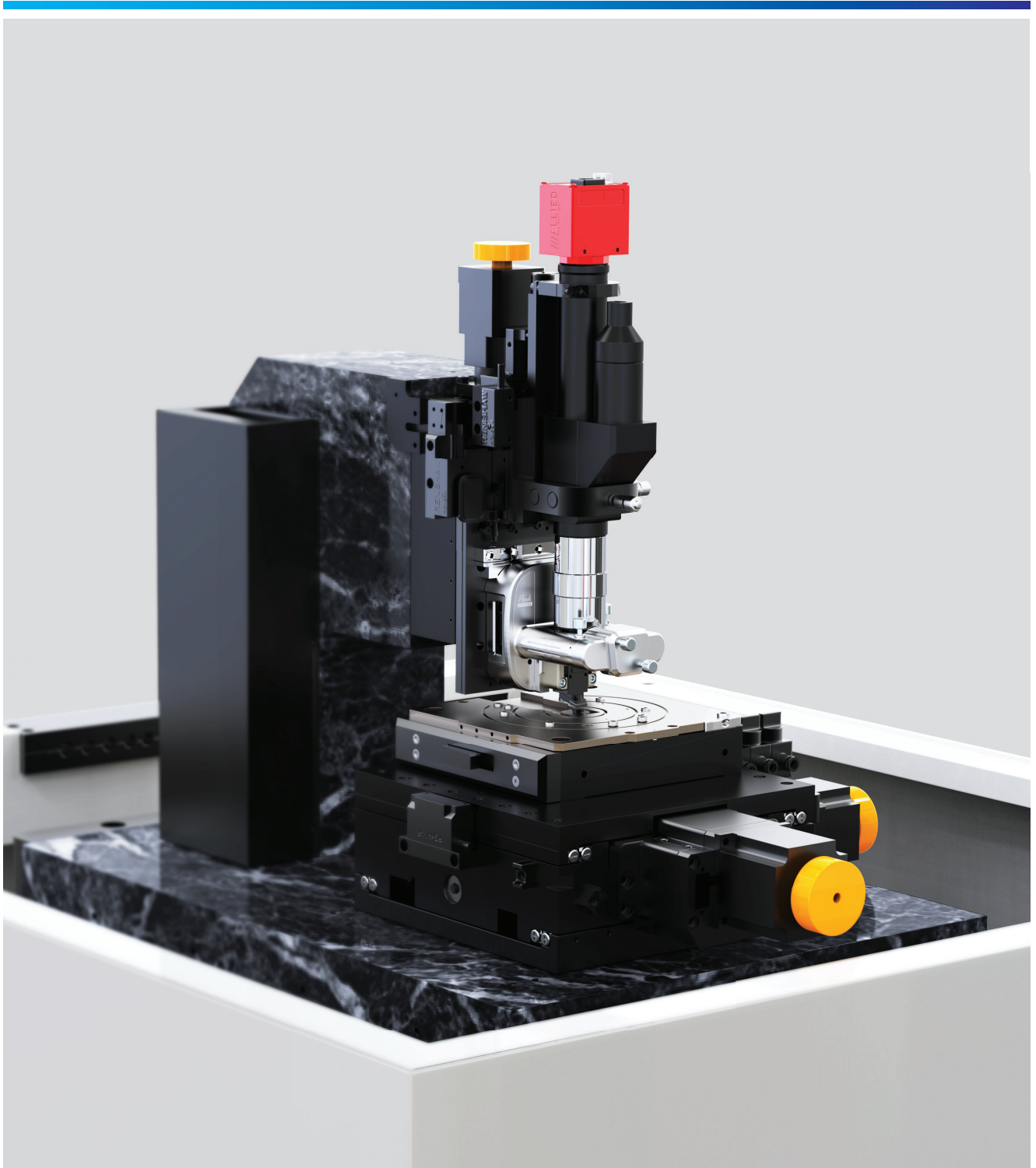


*Enabling Nanoscale Advances*



# Park NX20 Lite

The most affordable AFM system for wafer measurement and analysis with the latest NX performance

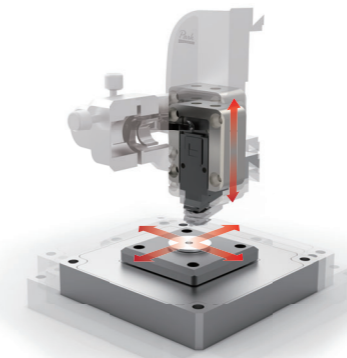




## Park NX20 Lite AFM Technology

### Flat Orthogonal XY Scanning without Scanner Bow

Park's Crosstalk Elimination scanner structure removes scanner bow, allowing flat orthogonal XY scanning regardless of scan location, scan rate, and scan size. It shows no background curvature even on flattest samples, such as an optical flat, and with various scan offsets. This provides you with a very accurate height measurement and precision nanometrology for the most challenging problems in research and engineering.



### Decoupled XY and Z Scanners

The fundamental difference between Park and its closest competitor is in the scanner architecture. Park's unique flexure based independent XY scanner and Z scanner design allows unmatched data accuracy in nano resolution further improved with NX AFM Head (Z scanner) powered by NX AFM electronic controller.

# Park NX20 Lite

Increase your productivity with our powerfully versatile AFM

### The Most Convenient Sample Measurements with MultiSample Scan

- Automated imaging of multiple samples in one pass
- Specially designed multi-sample chuck for the loading of up to 16 individual samples (optionally available)
- Fully motorized XY sample stage travels up to 150 mm x 150 mm

### Accurate XY Scan by Crosstalk Elimination

- Two independent, closed-loop XY and Z flexure scanners
- Flat and orthogonal XY scan with low residual bow
- More accurate height measurements enabled by NX electronic controller without any need for software processing

### Best Tip Life, Resolution and Sample Preservation by True Non-Contact™ Mode

- Fast Z-servo speed enabling True Non-Contact™ Mode
- Minimum tip wear for prolonged high-quality and high-resolution imaging

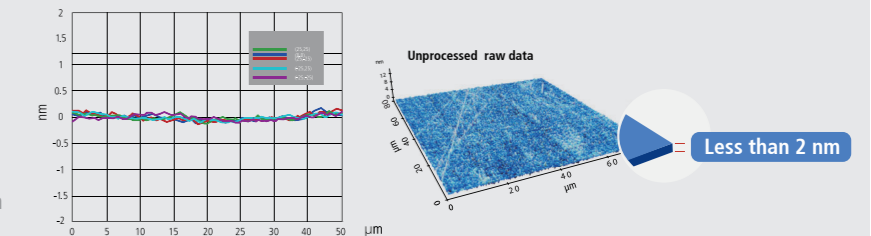
### Versatile Range of Modes and Options

- Comprehensive set of measurement modes and characterizations
- Expanded capabilities with optional accessories and upgrades
- Advanced electrical measurements for failure analysis (FA)

### Accurate Surface Measurement

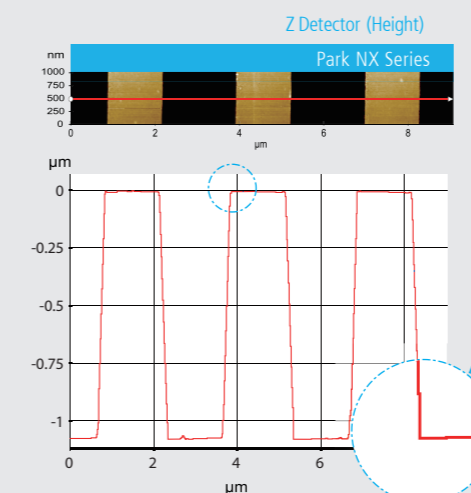
"Flat" sample surface as it is!

- Low residual bow
- No need for software processing
- Accurate results independent of scan location
- Less than 2 nm of out-of-plane motion with the NX electronic controller



### Industry Leading Low Noise Z Detector

Park AFMs are equipped with the most effective low noise Z detectors in the field, with a noise of 0.02 nm over large bandwidth. This produces highly accurate sample topography and no edge overshoot. Just one of the many ways Park NX series saves you time and gives you better data.



No creep effect

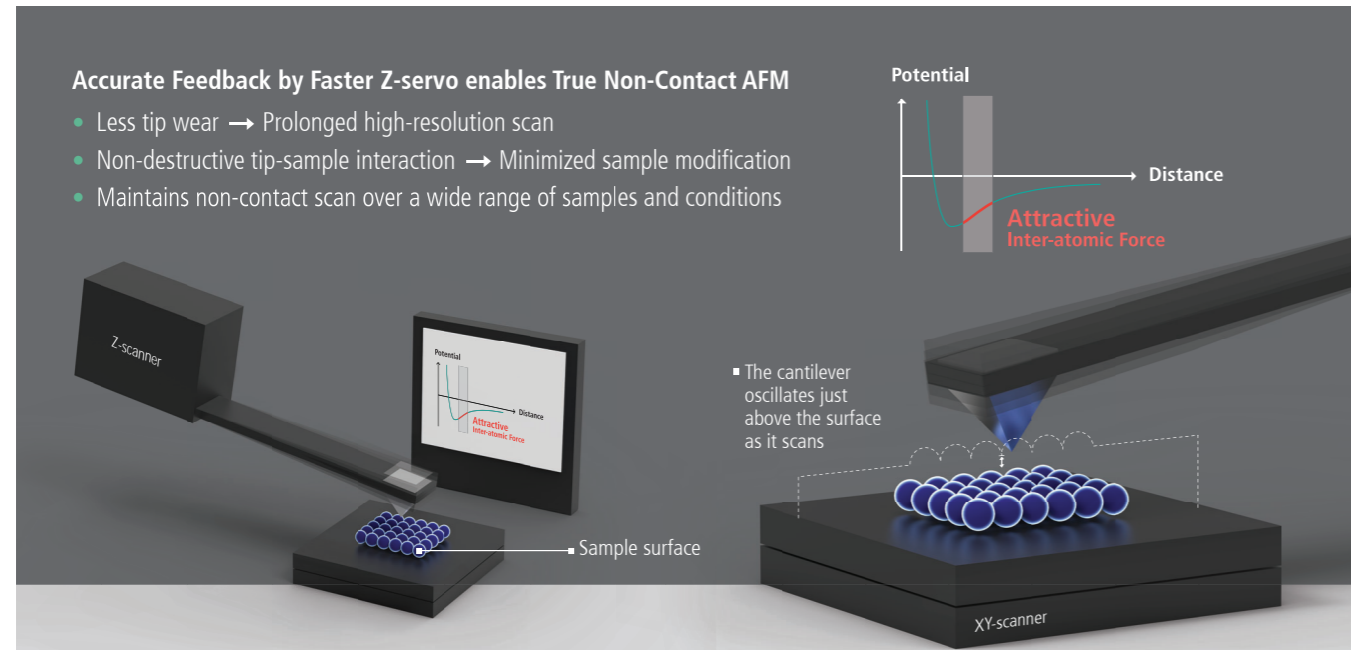
### Accurate Sample Topography Measured by Low Noise Z Detector

- Uses low noise Z detector signal for topography
- NX electronic controller provides low Z detector noise of 0.02 nm over large bandwidth
- Has no edge overshoot at the leading and trailing edges
- Needs calibration done only once at the factory

Sample: 1.2 μm Nominal Step Height  
(9 μm x 1 μm, 2048 pixels x 128 lines)

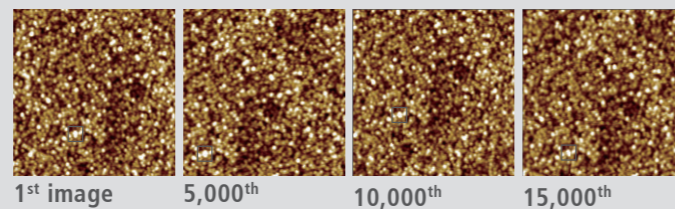
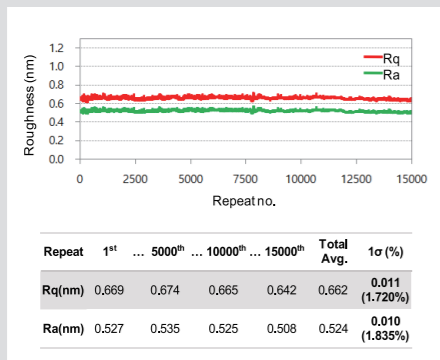
## True Non-Contact™ Mode

True Non-Contact™ Mode is a scan mode unique to Park AFM systems that produces high resolution and accurate data by preventing destructive tip-sample interaction during a scan.

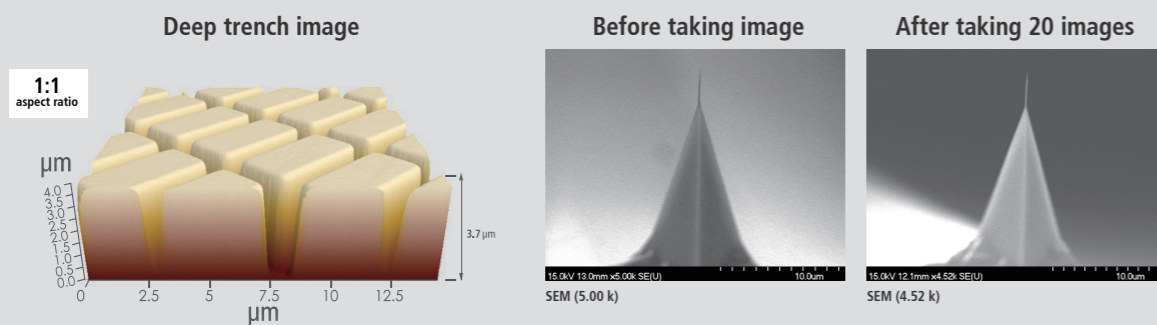


Unlike in contact mode, where the tip contacts the sample continuously during a scan, or in tapping mode, where the tip touches the sample periodically, a tip used in non-contact mode does not touch the sample.

Because of this, use of non-contact mode has several key advantages. Scanning at the highest resolution throughout imaging is now possible as the tip's sharpness is maintained. Non-contact mode avoids damaging soft samples as the tip and sample surface avoid direct contact.

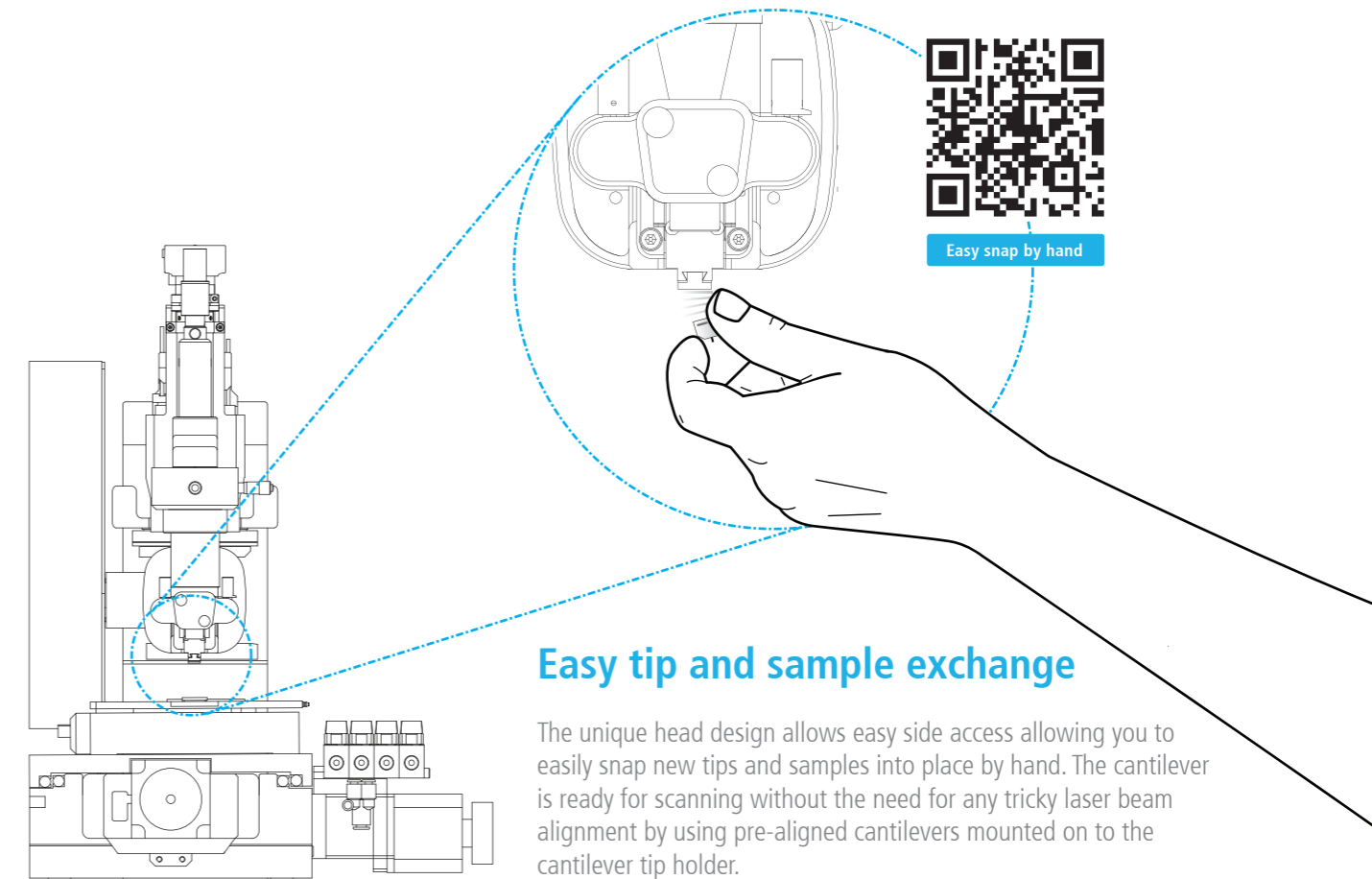


Furthermore, non-contact mode senses tip-sample interactions occurring all around the tip. Forces occurring laterally to tip approach to the sample are detected. Therefore, tips used in non-contact mode can avoid crashing into tall structures that may suddenly appear on a sample surface. Contact and tapping modes only detect the force coming from below the tip and are vulnerable to such crashes.



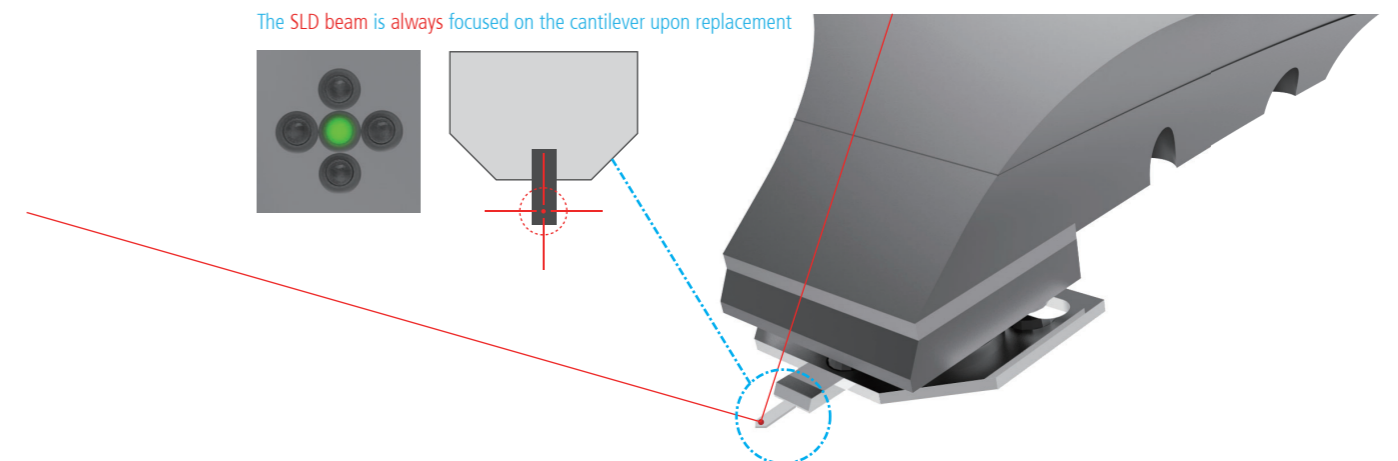
## Park NX20 Lite

Why the world's most accurate AFM is also the easiest to use



## Easy, intuitive SLD beam alignment

With our advanced pre-aligned cantilever holder, the SLD beam is focused on the cantilever upon placement. Furthermore, the natural on-axis, top-down view allows you to easily find the SLD spot. Since the SLD beam falls vertically onto the cantilever, you can intuitively move the SLD spot along the X- and Y- axis by rotating two positioning knobs. As a result, you can easily find the SLD and position it onto the position-sensitive photodiode using our operation software's beam alignment user interface. From there, all you will need is a minor adjustment to maximize the signal prior to starting data acquisition.





# Park Atomic Force Microscopy Modes

Get the data you need with Park's selection of scanning modes

TOPOGRAPHY IMAGING				
	Contact	Non-Contact	Tapping	
ELECTRICAL / MAGNETIC PROPERTIES				
	Conductive AFM	PinPoint Conductive AFM	IV Spectroscopy	Photocurrent Mapping
	Scanning Tunneling Microscopy	Scanning Spreading Resistance Microscopy	Scanning Capacitance Microscopy	Electrostatic Force Microscopy
NANOMECHANICAL PROPERTIES				
	Kelvin Probe Force Microscopy	Piezoresponse Force Microscopy	Magnetic Force Microscopy	Tunable Magnetic Field MFM
	Force Distance Spectroscopy	PinPoint Nanomechanical	Force Modulation Microscopy	Lateral Force Microscopy
OTHER PROPERTIES				
	Nanoindentation	Nanolithography	Nanomanipulation	
				● NOT AVAILABLE FOR THIS PRODUCT
Scanning Thermal Microscopy	Scanning Ion Conductance Microscopy			

### SRAM

Height

Current

**Scanning conditions**  
 Scan Mode: C-AFM  
 Scan Size: 1.5 μm x 1.5 μm  
 Cantilever: AD 2.8 AS (k= 2.8 N/m, f= 65 kHz)

Current measurement on SRAM with -1.5 V sample bias. P and N type of contact dot are well distinguished by IV spectroscopy measurements.

P1

P2

### Trench Etch Profile on MESA

Height

**Top dielectric trench etch profile on MESA on Si wafer**

**Scanning conditions**  
 Scan Mode: Non-contact  
 Scan Size: 6 μm x 6 μm  
 Cantilever: AR5T-NCHR (k= 42 N/m, f= 300 kHz)

Sample courtesy: Sang-Soo Je, Global Comm. Semiconductors, US

### Gallium nitride (GaN) LED wire

3D X:Y:Z scale = 1:1:1

Height

Peak to valley: 517.4 nm  
 RMS roughness: 184.7 nm

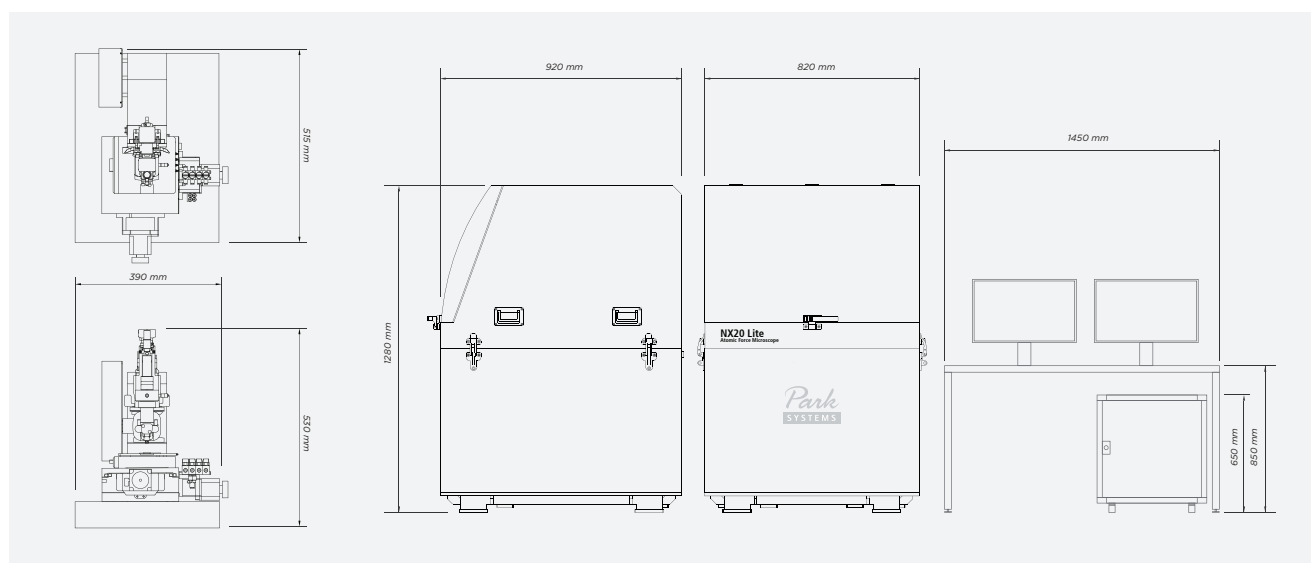
**Scanning conditions**  
 Scan Mode: Non-contact  
 Scan Size: 2 μm x 2 μm  
 Cantilever: OMCL-AC55TS (k= 85 N/m, f= 1.6 MHz)

Scanner	Z Scanner	XY Scanner	Stage	Z Stage	XY Stage
	Flexure guided high-force scanner Scan range: 15 µm (optional 30 µm)	Single module flexure XY-scanner with closed-loop control Scan range: 100 µm x 100 µm		Motorized Z stage travel range: 25.5 mm, optional precision encoder for better stage repeatability	Motorized XY stage travel range: 150 mm (200 mm optional), optional precision encoders for better XY stage repeatability

Vision	On-axis Optic with Vision	Sample Mount	Sample Dimension	Electronics	Signal Processing	Integrated Functions
	Objective lens: 10x magnification Field-of-view: 480 µm x 360 µm (with default 1.2 M pixel vision camera) 840 µm x 630 µm (with optional 5 M pixel vision camera)		Sample size: Up to 150 mm wafer sample Up to 200 mm wafer sample (Optional 200 mm Vacuum Sample Chuck)		ADC: 24-bit ADCs for X, Y, and Z scanner position sensor DAC: 20-bit DACs for X, Y, and Z scanner positioning	4 channels of flexible digital lock-in amplifier Spring constant calibration (Thermal method) Digital Q control

Options/Modes	Topography Imaging	Magnetic Properties	Electrical Properties	Mechanical Properties
	<ul style="list-style-type: none"> <li>Non-Contact</li> <li>Contact</li> <li>Tapping</li> </ul>	<ul style="list-style-type: none"> <li>Magnetic Force Microscopy (MFM)</li> </ul>	<ul style="list-style-type: none"> <li>Conductive AFM (C-AFM)</li> <li>I/V Spectroscopy</li> <li>Kelvin Probe Force Microscopy (KPFM)</li> <li>KPFM with High Voltage</li> <li>Scanning Capacitance Microscopy (SCM)</li> <li>Scanning Spreading-Resistance Microscopy (SSRM)</li> <li>Scanning Tunneling Microscopy (STM)</li> <li>Photo Current Mapping (PCM)</li> <li>Electrostatic Force Microscopy (EFM)</li> </ul>	<ul style="list-style-type: none"> <li>Force Modulation Microscopy (FMM)</li> <li>Nanoindentation</li> <li>Nanolithography</li> <li>Nanolithography with High Voltage</li> <li>Nanomaniipulation</li> <li>Lateral Force Microscopy (LFM)</li> <li>Force Distance (F/d) Spectroscopy</li> <li>Force Volume Imaging</li> </ul>
	<b>Dielectric/Piezoelectric Properties</b> <ul style="list-style-type: none"> <li>Piezoresponse Force Microscopy (PFM)</li> <li>PFM with High Voltage</li> <li>Piezoresponse Spectroscopy</li> </ul>	<b>Chemical Properties</b> <ul style="list-style-type: none"> <li>Chemical Force Microscopy with Functionalized Tip</li> <li>Electrochemical Microscopy (EC-AFM)</li> </ul>		

Software	Park SmartScan™	Park SmartAnalysis™	Accessories
	<ul style="list-style-type: none"> <li>AFM system control and data acquisition software</li> <li>Auto mode for quick setup and easy imaging</li> <li>Manual mode for advanced use and finer scan control</li> </ul>	<ul style="list-style-type: none"> <li>AFM data analysis software</li> <li>Stand-alone design—can install and analyze data away from AFM</li> <li>Capable of producing 3D renders of acquired data</li> </ul>	<ul style="list-style-type: none"> <li>Electrochemistry Cell</li> <li>Universal Liquid Cell with Temperature Control</li> <li>Temperature Controlled Stages</li> <li>Magnetic Field Generator</li> </ul>



**Note:** All specifications are subject to change without notice. Please visit our website for the most up-to-date specifications.

## Committed to Contribute to Impactful Science and Technological Development

More than 25 years ago, the foundations of Park Systems were laid at Stanford University, where Park Systems' founder, Dr. Sang-il Park, worked in Prof. Calvin Quate's group; the group that invented the world's first AFM. After years of development, Dr. Park introduced the first commercial AFM to the world, thus starting the successful path of Park Systems. With good foresight, a superior product and keen business acumen, Park has positioned themselves as the dominant industry leader in AFM Nanoscale Metrology and in 2020, Park Systems will roll out their most exciting line of AFM products in their history.

Park Systems continuously strives to live up to the innovative spirit of its origin. Throughout its long journey, the company has been committed to provide advanced, accurate, and reliable AFM instrumentation, with revolutionary features such as True Non-Contact™ mode and PinPoint™ Nanomechanical AFM. Cutting-edge AFM automation features, like SmartScan™, make Park Systems AFMs not only extremely easy to use, but they also enable users to obtain outstanding results faster, more efficiently and more accurately.

## Park Systems

*Enabling Nanoscale Advances*

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